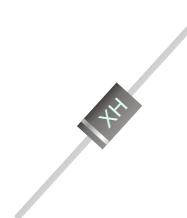


FEATURES

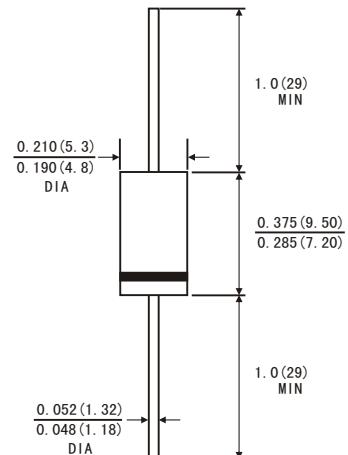
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters,
free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260 C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and
WEEE 2002/96/EC

MECHANICAL DATA

- Case: JEDEC DO-201AD molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.041ounce, 1.15 grams



DO-201AD



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	SR 520L	SR 530L	SR 540 L	SR 545L	SR 560L	SR 580L	SR 5100L	SR 5150L	SR 5200L	Units								
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	45	60	80	100	150	200	Volts								
Maximum RMS voltage	V _{RMS}	14	21	28	31	42	57	71	105	140	Volts								
Maximum DC blocking voltage	V _{DC}	20	30	40	45	60	80	100	150	200	Volts								
Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1)	I _(AV)	5.0									Amps								
Peak forward surge current 8.3mA single half sine-wave superimposed on rated load (JEDEC method at rated I _F)	I _{FSM}	150.0									Amps								
Maximum instantaneous forward voltage at 5.0 A(Note 1)	V _F	0.40			0.5	0.68		0.80	0.85	Volts									
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1) $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	IR	0.5 50 25									mA								
Typical junction capacitance(Note 3)	C _J	500			400						pF								
Typical thermal resistance (Note 2)	R _{θJA} R _{θJL}	25.0 8.0									°C/W								
Operating junction temperature range	T _J	-65 to +150									°C								
Storage temperature range	T _{STG}	-65 to +150									°C								

Notes: 1.Pulse test: 300μ s pulse width,1% duty cycle

2.Thermal resistance from junction to lead vertical PC.B. mounted , 0.375"(9.5mm)lead length

3.Measured at 1MHz and reverse voltage of 4.0 volts

RATINGS AND CHARACTERISTIC CURVES

FIG.1-FORWARD CURRENT DERATING CURVE

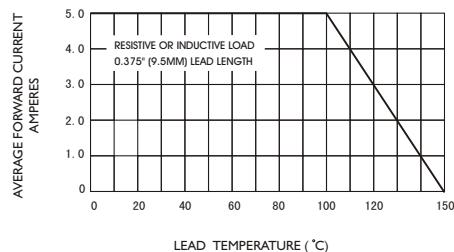


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

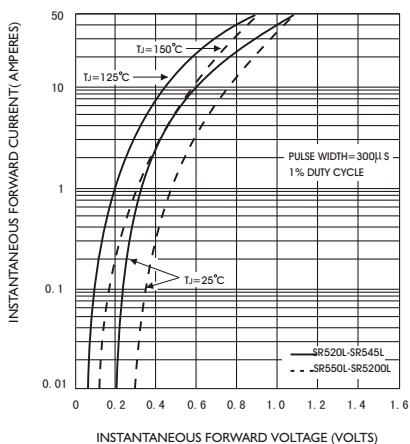


FIG.5-TYPICAL JUNCTION CAPACITANCE

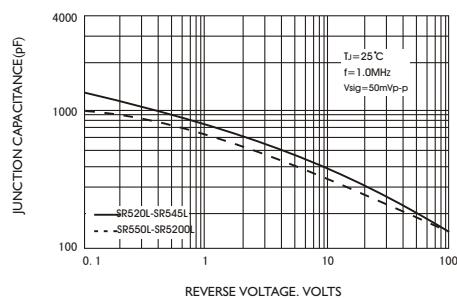


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

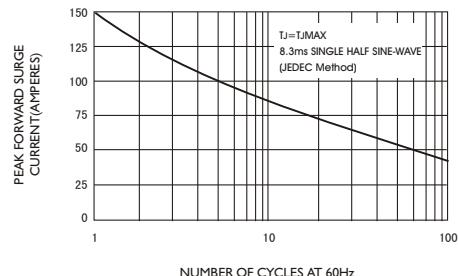


FIG.4-TYPICAL REVERSE CHARACTERISTICS

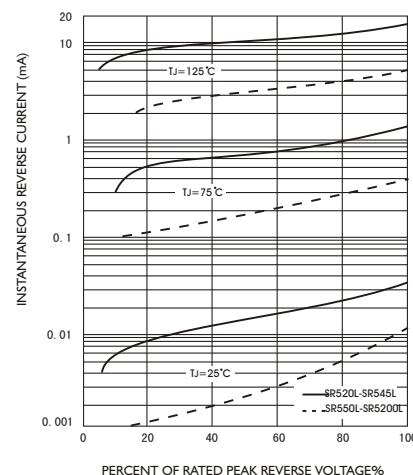


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

